



#### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(ON)</sub> max	I <sub>D</sub> max T <sub>A</sub> = +25°C		
60V	$7.5\Omega$ @ $V_{GS} = 5V$	210mA		

### **Description**

This MOSFET has been designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

### **Applications**

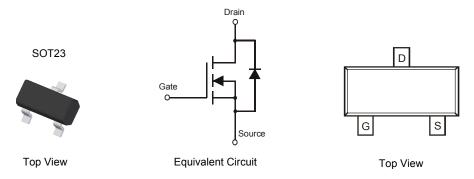
- Motor Control
- Power Management Functions

#### **Features**

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- · Fast Switching Speed
- Small Surface Mount Package
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Notes 3 & 4)
- Qualified to AEC-Q101 standards for High Reliability

#### **Mechanical Data**

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 @3
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)



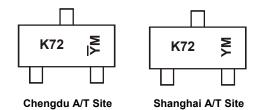
#### Ordering Information (Note 5)

Part Number	Compliance	Case	Packaging
2N7002-7-F	Standard	SOT23	3,000/Tape & Reel
2N7002-13-F	Standard	SOT23	10,000/Tape & Reel
2N7002Q-7-F	Automotive	SOT23	3,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Product manufactured with Date Code V12 (week 50, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V12 are built with Non-Green Molding Compound and may contain Halogens or Sb<sub>2</sub>O<sub>3</sub> Fire Retardants.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**



K72 = Product Type Marking Code

YM = Date Code Marking for SAT (Shanghai Assembly/ Test site)

YM = Date Code Marking for CAT (Chengdu Assembly/ Test site)

Y or Y = Year (ex: A = 2013)

M = Month (ex: 9 = September)

Date Code Key

Year	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012	2013	2014	2015	2016	2017
Code	Ν	Р	R	S	Т	U	V	W	X	Υ	Z	Α	В	С	D	Е
Month	Jan	F	eb	Mar	Apr	M	lay	Jun	Jul	A	ug	Sep	Oct	N	ov	Dec
Code	1		2	3	4		5	6	7		8	9	0	ı	V	D



## **Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V <sub>DSS</sub>	60	V
Drain-Gate Voltage R <sub>GS</sub> ≤ 1.0MΩ			$V_{DGR}$	60	V
Gate-Source Voltage		Continuous Pulsed	V <sub>GSS</sub>	±20 ±40	V
Continuous Drain Current (Note 6) V <sub>GS</sub> = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +85^{\circ}C$ $T_A = +100^{\circ}C$	I <sub>D</sub>	170 120 105	mA
Continuous Drain Current (Note 7) V <sub>GS</sub> = 10V	Steady State	$T_A = +25^{\circ}C$ $T_A = +85^{\circ}C$ $T_A = +100^{\circ}C$	lo	210 150 135	mA
Maximum Body Diode Forward Current (Note 7)		Pulsed ntinuous	I <sub>S</sub>	0.5 2	А
Pulsed Drain Current (10µs pulse, duty cycle = 1%)	I <sub>DM</sub>	800	mA		

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units	
Total Power Dissipation	(Note 6)	D-	370	mW	
Total Fower Dissipation	(Note 7)	P <sub>D</sub>	540		
Thermal Desistance, Junction to Ambient	(Note 6)	0	348		
Thermal Resistance, Junction to Ambient	(Note 7)	R <sub>0JA</sub>	241	°C/W	
Thermal Resistance, Junction to Case	(Note 7)	R <sub>eJC</sub>	91		
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

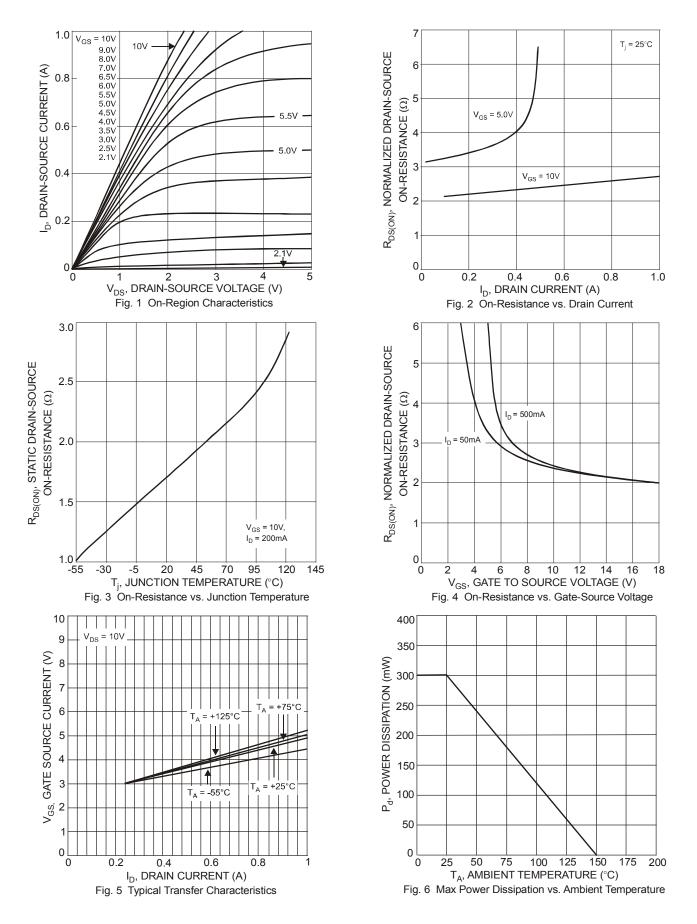
## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	60	70	_	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current	@ T <sub>C</sub> = +25°C @ T <sub>C</sub> = +125°C	I <sub>DSS</sub>	_	_	1.0 500	μA	V <sub>DS</sub> = 60V, V <sub>GS</sub> = 0V
Gate-Body Leakage		I <sub>GSS</sub>	_	_	±10	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage		V <sub>GS(th)</sub>	1.0	_	2.5	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$
Static Drain-Source On-Resistance	@ T <sub>J</sub> = +25°C @ T <sub>J</sub> = +25°C @ T <sub>J</sub> = +125°C	R <sub>DS(ON)</sub>	_	3.2 — 4.4	7.5 5.0 13.5	Ω	$V_{GS} = 5.0V$ , $I_D = 0.05A$ $V_{GS} = 10V$ , $I_D = 0.5A$ $V_{GS} = 10V$ , $I_D = 0.5A$
On-State Drain Current		I <sub>D(ON)</sub>	0.5	1.0	_	Α	$V_{GS} = 10V, V_{DS} = 7.5V$
Forward Transconductance		<b>g</b> FS	80	_	_	mS	$V_{DS} = 10V, I_D = 0.2A$
Diode Forward Voltage		$V_{SD}$	_	0.78	1.5	V	$V_{GS} = 0V, I_{S} = 115mA$
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance		C <sub>iss</sub>		22	50	pF	\/ - 05\/ \/ - 0\/
Output Capacitance		Coss		11	25	pF	$V_{DS} = 25V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance		Crss		2.0	5.0	pF	1 - 1.0WI12
Gate resistance		Rg	_	120	_	Ω	$V_{DS} = 0V, V_{GS} = 0V,$ f = 1.0MHz
Total Gate Charge (V <sub>GS</sub> = 4.5V)		$Q_g$		223	_		
Gate-Source Charge		$Q_{gs}$		82	_	рC	$V_{DS} = 10V, I_D = 250mA$
Gate-Drain Charge		$Q_{gd}$		178	_		
SWITCHING CHARACTERISTICS (Note 9)							
Turn-On Delay Time		t <sub>D(on)</sub>		2.8	_		\/ = 20\/
Turn-On Rise Time		t <sub>r</sub>		3.0	_	ns	$V_{DD} = 30V, I_D = 0.2A,$
Turn-Off Delay Time	<u> </u>	t <sub>D(off)</sub>		7.6	_	115	$R_L = 150\Omega$ , $V_{GEN} = 10V$ , $R_{GEN} = 25\Omega$
Turn-Off Fall Time		t <sub>f</sub>		5.6	_		1.GEN - 2022

Notes:

- 6. Device mounted on FR-4 PCB, with minimum recommended pad layout
  7. Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
  8. Short duration pulse test used to minimize self-heating effect.
  9. Guaranteed by design. Not subject to product testing.

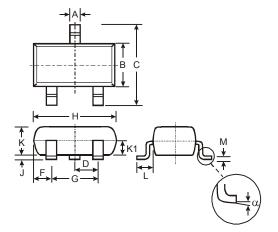






## **Package Outline Dimensions**

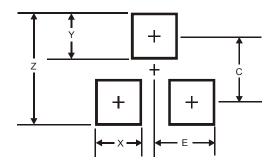
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23								
Dim	Min	Max	Тур					
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
K	0.903	1.10	1.00					
K1	-	-	0.400					
L	0.45	0.61	0.55					
М	0.085	0.18	0.11					
α	0°	8°	-					
All Dimensions in mm								

# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
Χ	0.8
Υ	0.9
С	2.0
Е	1.35



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